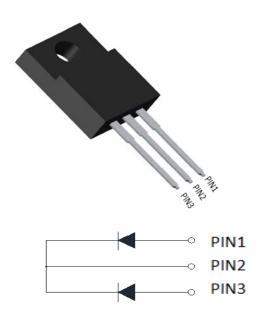
MBR40100FCT



Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: ITO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

■ Maximum Ratings (T_j =25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR40100FCT
Device marking code			MBR40100FCT
Repetitive Peak Reverse Voltage	V_{RRM}	V	100
Average Rectified Output Current @60Hz sine wave, R-load, Tc(FIG.1)	Io	А	40
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Tj=25°C	I _{FSM}	А	300
Current Squared Time @1ms≤t≤8.3ms Tj=25˚C	l²t	A ² s	373
Storage Temperature	T_{stg}	°C	-55 ~ +175
Junction Temperature	Tj	°C	-55 ~ + 175

■Electrical Characteristics $(T_j=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR40100FCT
Maximum instantaneous forward voltage drop per diode	$V_{\sf FM}$	V	I _{FM} =20.0A	0.85
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _{RRM} Tj=25℃	0.1
	I _{RRM2}		V _{RM} =V _{RRM} Tj=125℃	20

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS

MBR40100FCT

■Thermal Characteristics $(T_j=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PA	RAMETER	SYMBOL	UNIT	MBR40100FCT
Thermal Resistance	Between junction and case	R _{θJ-C}	°C/W	4.0

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR40100FCT	Approximate 1.6	50	1000	5000	Tube

■Characteristics (Typical)

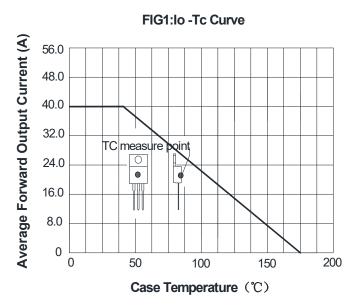


FIG2:Surge Forward Current Capability

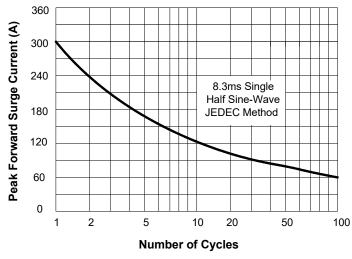


FIG3: Forward Voltage

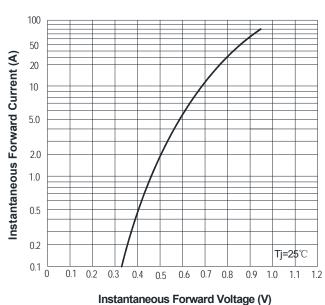
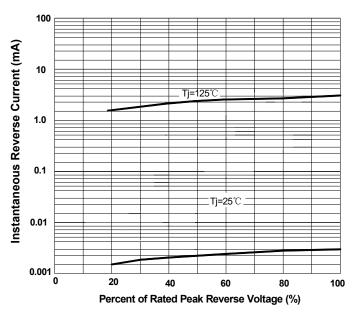


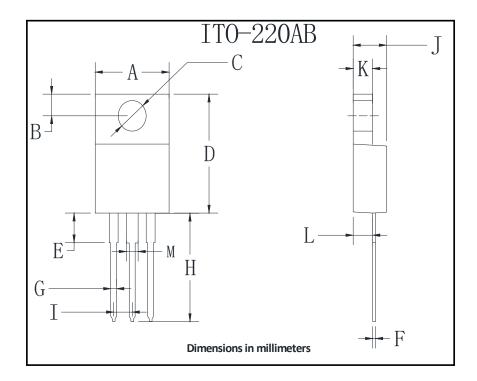
FIG.4: Instantaneous Reverse Characteristics







■Outline Dimensions



ITO-220AB					
Dim	Min	Max			
Α	9.8	10.2			
В	2.25	2.75			
С	2.95	3.45			
D	14.75	15.25			
Е	3.05	3.95			
F	0.45	0.75			
G	0.45	0.75			
Н	13.4	14.2			
I	2.35	2.75			
J	4.3	4.8			
K	2.58	2.82			
L	2.58	2.82			
M	1.47	1.77			



MBR40100FCT

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